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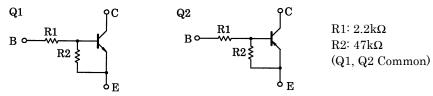
TOSHIBA Transistor Silicon NPN/PNP Epitaxial Type (PCT Process) (Transistor with Built-in Bias Resistor)

RN4985

Switching, Inverter Circuit, Interface Circuit and Driver Circuit Applications

- Including two devices in US6 (ultra super mini type with 6 leads)
- With built-in bias resistors
- Simplify circuit design •
- Reduce a quantity of parts and manufacturing process

Equivalent Circuit and Bias Resister Values

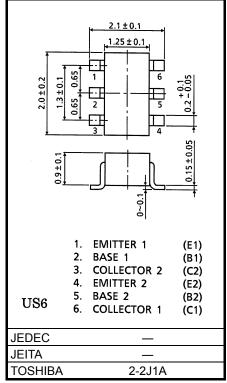


Q1 Absolute Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	50	V
Collector-emitter voltage	V _{CEO}	50	V
Emitter-base voltage	V _{EBO}	5	V
Collector current	Ι _C	100	mA

Q2 Absolute Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	-50	V
Collector-emitter voltage	V _{CEO}	-50	V
Emitter-base voltage	V _{EBO}	-5	V
Collector current	Ι _C	-100	mA



Weight: 6.8 mg (typ.)

Unit: mm

Q1, Q2 Common Absolute Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Collector power dissipation	P _C *	200	mW
Junction temperature	Тј	150	°C
Storage temperature range	T _{stg}	−55 to 150	°C

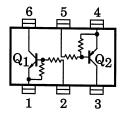
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

* Total rating

Marking

Equivalent Circuit (Top View)



Q1 Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	_	V _{CB} = 50V, I _E = 0	_	_	100	nA
	ICEO	_	V _{CE} = 50V, I _B = 0	_	—	500	ПА
Emitter cut-off current	I _{EBO}	_	V _{EB} = 5V, I _C = 0	0.078	—	0.145	mA
DC current gain	h _{FE}		V _{CE} = 5V, I _C = 10mA	80	_	_	_
Collector-emitter saturation voltage	V _{CE (sat)}		I _C = 5mA, I _B = 0.25mA	_	0.1	0.3	V
Input voltage (ON)	V _{I (ON)}		V _{CE} = 0.2V, I _C = 5mA	0.6	_	1.1	V
Input voltage (OFF)	VI (OFF)		V _{CE} = 5V, I _C = 0.1mA	0.5	_	0.8	V
Transition frequency	f _T		V _{CE} = 10V, I _C = 5mA	_	250	_	MHz
Collector output capacitance	C _{ob}	_	V _{CB} = 10V, I _E = 0, f = 1 MHz	—	3	6	pF

Q2 Electrical Characteristics (Ta = 25°C)

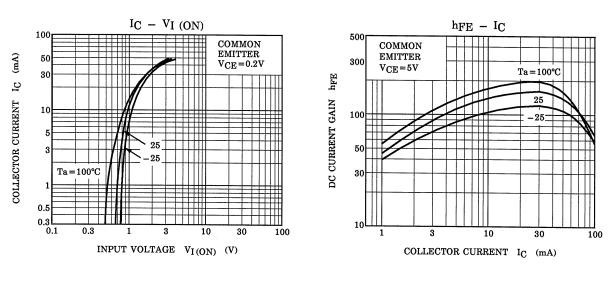
Characteristic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	_	$V_{CB} = -50V, I_E = 0$	_	_	-100	nA
	ICEO		$V_{CE} = -50V, I_B = 0$	_	—	-500	11A
Emitter cut-off current	I _{EBO}		$V_{EB} = -5V, I_C = 0$	-0.078	—	-0.145	mA
DC current gain	h _{FE}		V _{CE} = -5V, I _C = -10mA	80	—	—	_
Collector-emitter saturation voltage	V _{CE (sat)}		I _C = −5mA, I _B = −0.25mA	_	-0.1	-0.3	V
Input voltage (ON)	V _{I (ON)}	-	$V_{CE} = -0.2V, I_{C} = -5mA$	-0.6	_	-1.1	V
Input voltage (OFF)	VI (OFF)		$V_{CE} = -5V, I_C = -0.1mA$	-0.5	—	-0.8	V
Transition frequency	f _T		V _{CE} = −10V, I _C = −5mA	_	200	_	MHz
Collector output capacitance	C _{ob}	_	V _{CB} = -10V, I _E = 0, f = 1MHz	_	3	6	pF

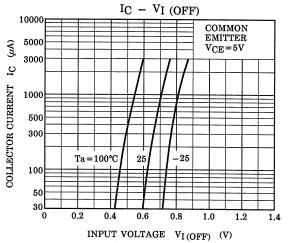
Q1, Q2 Common Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Input resistor	R1	_	—	1.54	2.2	2.86	kΩ
Resistor ratio	R1/R2	_	_	0.0421	0.0468	0.0515	—

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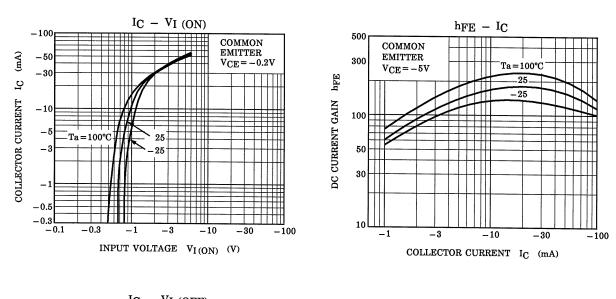
Q1

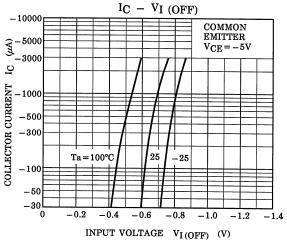




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Q2





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